BAV19WS, BAV20WS, BAV21WS

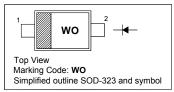
SURFACE MOUNT FAST SWITCHING DIODE

Features

- · Fast Switching Speed
- Surface Mount Package Ideally Suited for automatic Insertion
- For General Purpose Switching Applications
- High Conductance

PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode



Absolute Maximum Ratings (T_a = 25 °C)

Symbol	Value	Unit	
	120	V	
V_{RRM}	200		
	250		
	100		
V_R	150	V	
	200		
Io	200	mA	
I _{FM}	400	mA	
I _{FRM}	I _{FRM} 625		
1	2.5	А	
IFSM	0.5		
P _{tot}	200	mW	
T_j, T_{stg}	- 65 to + 150	°C	
	V _{RRM} V _R I _O I _{FM} I _{FRM} I _{FSM} P _{tot}	V _{RRM} 200 250 100 V _R 150 200 I _O 200 I _{FM} 400 I _{FRM} 625 I _{FSM} 0.5 P _{tot} 200	

Characteristics at T_a = 25 °C

Parameter		Symbol	Min.	Max.	Unit
Reverse Breakdown Voltage					
at I _R = 100 μA	BAV19WS	$V_{(BR)R}$	120	-	V
·	BAV20WS		200	-	
	BAV21WS		250	-	
Reverse Current					
at V _R = 100 V	BAV19WS	I _R	-	100	nA
at V _R = 150 V	BAV20WS		-	100	
at V _R = 200 V	BAV21WS		-	100	
Forward Voltage					
at I _F = 100 mA		V_{F}	-	1	V
at I _F = 200 mA			-	1.25	
Total Capacitance		C		5	nE
at f = 1 MHz		C_T	1	5	pF
Reverse Recovery Time at $I_F = I_R = 30$ mA, $I_{RR} = 0.1$ X I_R , $R_L = 100$ Ω		t _{rr}	-	50	ns



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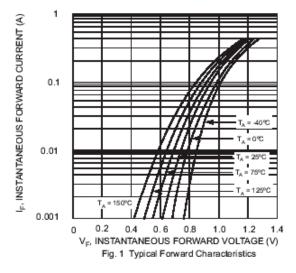


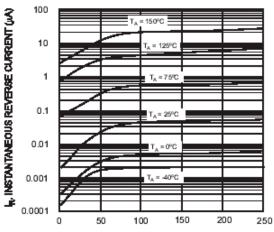




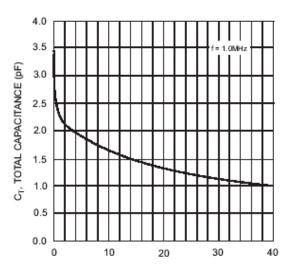


Dated: 07/04/2009

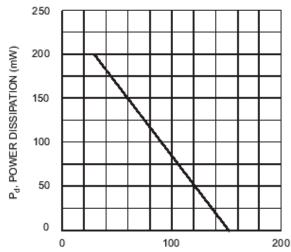




V_R, INSTANTANEOUS REVERSE VOLTAGE (V) Fig. 2 Typical Reverse Characteristics



V_R, REVERSE VOLTAGE (V) Fig. 3 Typical Capacitance vs. Reverse Voltage



T_A, AMBIENT TEMPERATURE (°C) Fig. 4 Power Derating Curve, Total Package



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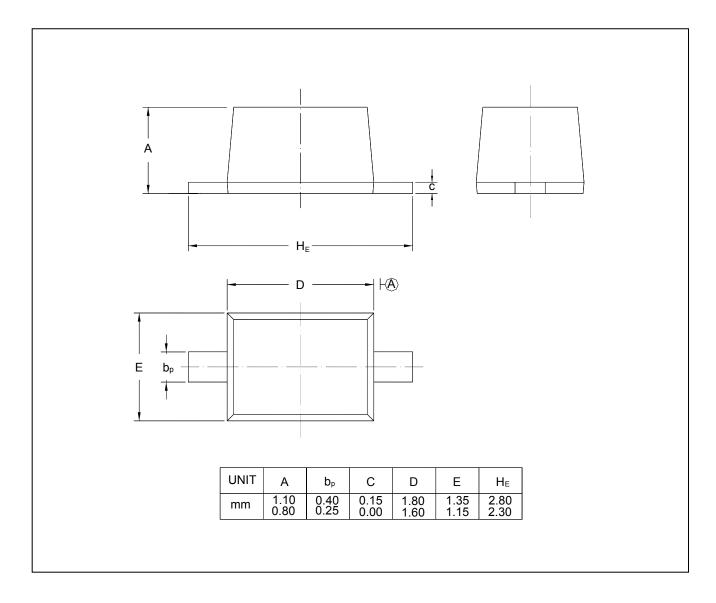




PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD-323



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